

Electrical Characteristics @ Tj = 25°C (Unless Otherwise Specified) Symbol Parameter Min. Typ. Max. Units Test Conditions									
Symbol	Parameter	Min.	тур.	wax.		Test Conditions			
BV _{DSS}	Drain-to-Source Breakdown Voltage	100			V	$V_{GS} = 0V, I_{D} = 1.0mA$			
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.10		V/°C	Reference to 25° C, I _D = 1.0mA			
R _{DS(on)}	Static Drain-to-Source On-Resistance			0.30	Ω	V _{GS} = 10V, I _{D2} = 3.5A ④			
				0.35	52	V _{GS} = 10V, I _{D1} = 6.0A ④			
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	V_{DS} = V_{GS} , I_D = 250 μ A			
Gfs	Forward Transconductance	1.5			S	V _{DS} = 15V, I _{D2} = 3.5A ④			
I _{DSS}	Zero Gate Voltage Drain Current			25		V_{DS} = 80 V, V_{GS} = 0V			
				250	μA	$V_{DS} = 80V, V_{GS} = 0V, T_{J} = 125^{\circ}C$			
I _{GSS}	Gate-to-Source Leakage Forward			100	nA	V _{GS} = 20V			
	Gate-to-Source Leakage Reverse			-100		V _{GS} = -20V			
Q_{G}	Total Gate Charge	7.7		18		I _{D1} = 6.0A			
Q_{GS}	Gate-to-Source Charge	0.7		4.0	nC	V _{DS} = 50V			
Q_{GD}	Gate-to-Drain ('Miller') Charge	2.0		9.0		V _{GS} = 10V			
t _{d(on)}	Turn-On Delay Time			40		V _{DD} = 35V			
tr	Rise Time			70	ns	I _{D1} = 6.0A			
t _{d(off)}	Turn-Off Delay Time			40		R _G = 7.5Ω			
t _f	Fall Time			70		V _{GS} = 10V			
Ls +L _D	Total Inductance		7.0		nH	Measured from Drain lead (6mm / 0.25 in from package) to Source lead (6mm/ 0.25 in from package) with Source wire internally bonded from Source pin to Drain pin			
C _{iss}	Input Capacitance		350			V _{GS} = 0V			
C _{oss}	Output Capacitance		150		pF	V _{DS} = 25V			
C _{rss}	Reverse Transfer Capacitance		24			f = 1.0MHz			

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Source-Drain Diode Ratings and Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
I _S	Continuous Source Current (Body Diode)			6.0	Δ		
I _{SM}	Pulsed Source Current (Body Diode) ①			24	A		
V _{SD}	Diode Forward Voltage			1.8	V	$T_J = 25^{\circ}C, I_S = 6.0A, V_{GS} = 0V$	
t _{rr}	Reverse Recovery Time			240	ns	$T_J = 25^{\circ}C, I_F = 6.0A, V_{DD} \le 50V$	
Q _{rr}	Reverse Recovery Charge			2.0	μC	di/dt = 100A/µs ④	
t _{on}	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by $L_{\text{S}}\text{+}L_{\text{D}})$					

Thermal Resistance

Symbol	Parameter	Min.	Тур.	Max.	Units	
$R_{ ext{ heta}JC}$	Junction-to-Case			6.25	°C/W	
R _{0JA}	Junction-to-Ambient (Typical Socket Mount)			175	°C/W	

Footnotes:

- ① Repetitive Rating; Pulse width limited by maximum junction temperature.
- $@~V_{\text{DD}}$ = 25V, starting T_{J} = 25°C, Peak I_L = 2.2A, L = 100 μH
- 3 $~I_{SD}$ \leq 6.0A, di/dt \leq 110A/µs, V_{DD} \leq 100V, T_{J} \leq 150°C, Suggested R_{G} = 7.5 Ω
- (4) Pulse width \leq 300 µs; Duty Cycle \leq 2%



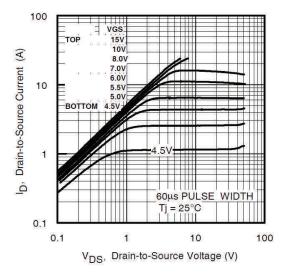


Fig 1. Typical Output Characteristics

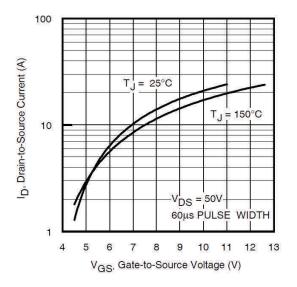
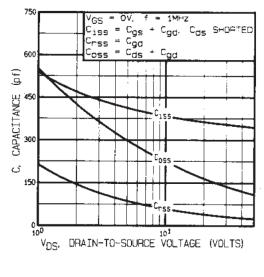
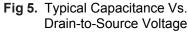


Fig 3. Typical Transfer Characteristics





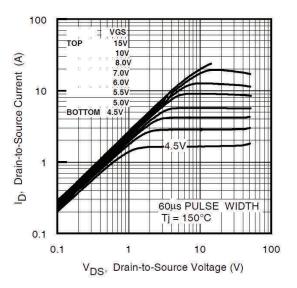


Fig 2. Typical Output Characteristics

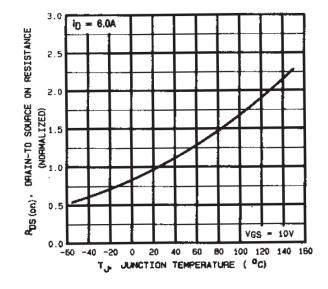
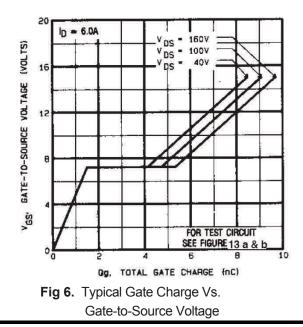
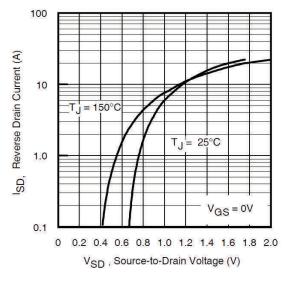
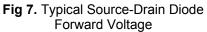


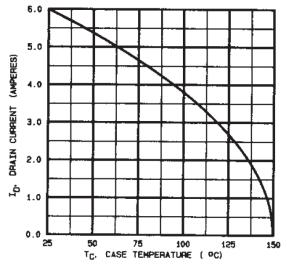
Fig 4. Normalized On-Resistance Vs. Temperature













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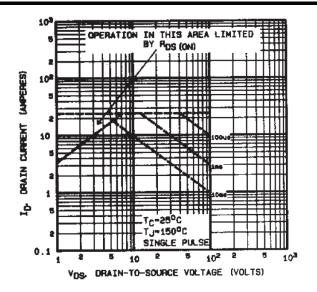
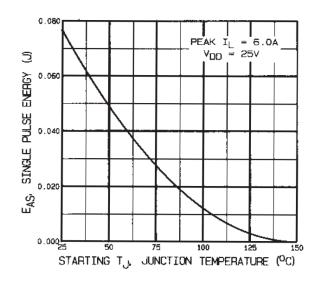
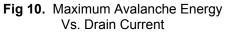


Fig 8. Maximum Safe Operating Area





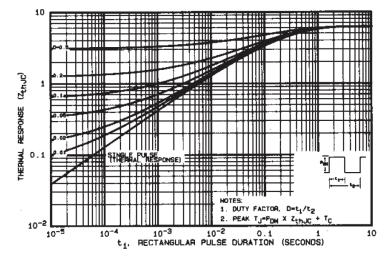


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

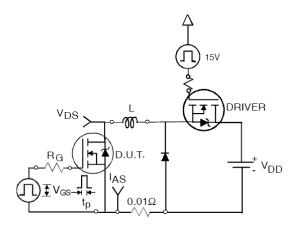
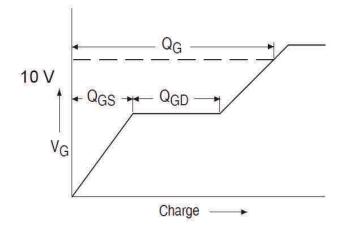


Fig 12a. Unclamped Inductive Test Circuit





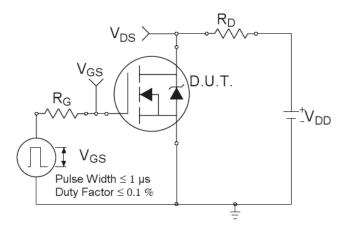
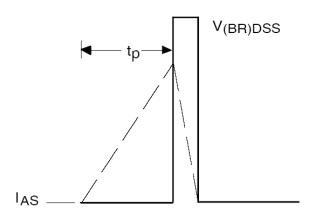
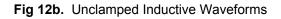


Fig 14a. Switching Time Test Circuit





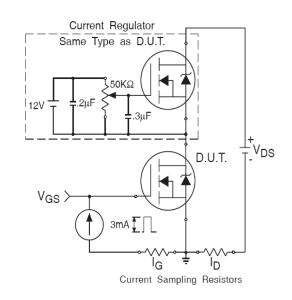
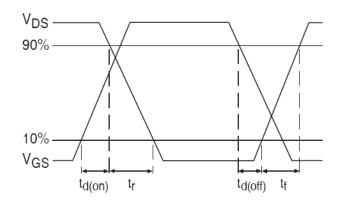
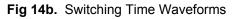


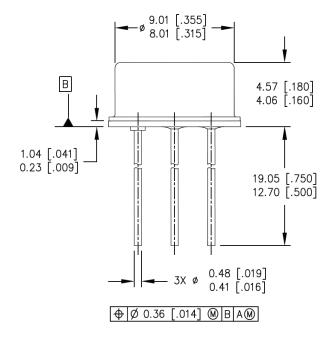
Fig 13b. Gate Charge Test Circuit

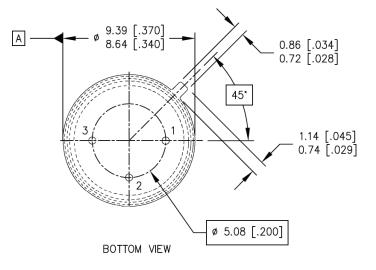






Case Outline and Dimensions - TO-205AF (TO-39)





LEGEND 1- SOURCE 2- GATE 3- DRAIN (CONNECTED TO THE CASE)



Infineon Technologies Service Center: USA Tel: +1 (866) 951-9519 and International Tel: +49 89 234 65555 Leominster, Massachusetts 01453, USA Tel: +1 (978) 534-5776 San Jose, California 95134, USA Tel: +1 (408) 434-5000 Data and specifications subject to change without notice.

SIDE VIEW

- 1. DIMENSIONING AND TOLERANCING PER ASME 14.5M-1994.
- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 3. CONTROLLING DIMENSION: INCH.
- 4. CONFORMS TO JEDEC OUTLINE TO-205AF (TO-39).



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